

#### NOT RECOMMENDED FOR NEW DESIGN **CONTACT US**



DMP4025LSD

#### 40V DUAL P-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

BVDSS	Rds(ON) Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C	
-40V	25mΩ @ V <sub>GS</sub> = -10V	-7.6A	
	45mΩ @ V <sub>GS</sub> = -4.5V	-6.0A	

## **Description and Applications**

This MOSFET has been designed to minimize the on-state resistance yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor controls
- Backlighting
- DC-DC converters
- Printer equipment

#### **Features and Benefits**

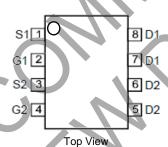
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low RDS(ON) Minimizes Conduction Losses
- Fast Switching Speed Minimizes Switching Losses
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
  - https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMP4025LSDQ)

#### **Mechanical Data**

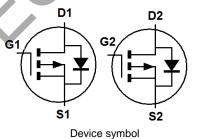
- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.074 grams (Approximate)



Top View



Pin-Out



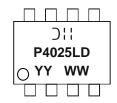
## Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMP4025LSD-13	SO-8	2500	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>
  4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



☐ = Manufacturer's Marking P4025LD = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 23 = 2023)WW = Week (01 to 53)



# **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	-40	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current	Vgs = -10V	(Notes 6 & 8)	ΙD	-7.6	
		T <sub>A</sub> = +70°C (Notes 6 & 8)		-6.1	
		(Notes 5 & 8)		-5.8	
		(Notes 5 & 9)		-6.9	Α
Pulsed Drain Current	Vgs = -10V	(Notes 7 & 8)	I <sub>DM</sub>	-28.0	
Continuous Source Current (Body Diode)		(Notes 6 & 8)	Is	-7.6	]
Pulsed Source Current (Body Diode)		(Notes 7 & 8)	I <sub>SM</sub>	-28.0	
Avalanche Current (Note 8) L = 0.3mH		(Note 11)	las	-23	Α
Avalanche Energy (Note 8) L = 0.3mH		(Note 11)	Eas	79	mJ

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

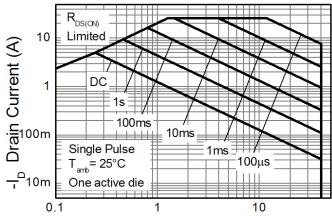
Characteristic	Symbol	Value	Unit	
Danier Biacinetics	(Notes 6 & 8)		2.14	
Power Dissipation Linear Derating Factor	(Notes 5 & 8)	Pb	1.25	W
Linear Derailing Factor	(Notes 5 & 9)		1.8	
	(Notes 6 & 8)		58	
Thermal Resistance, Junction to Ambient	(Notes 5 & 8)	R <sub>0</sub> JA	100	90.44/
	(Notes 5 & 9)		70	°C/W
Thermal Resistance, Junction to Lead	(Notes 8 & 10)	Rejl	51	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes:

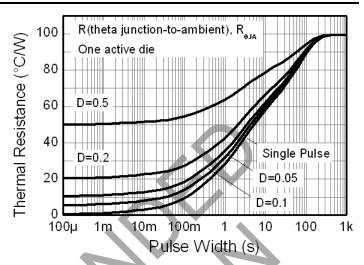
- 5. For a device surface mounted on 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage measured when operating in a steady-state condition.
   Same as note (5), except the device is measured at t ≤ 10 sec.
   Same as note (6), except the device is pulsed with D = 0.02 and pulse width 300μs.
   For a dual device with one active die.
   For a device with two active die running at equal power.
   Thermal resistance from junction to solder-point (at the end of the drain lead).
   I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.



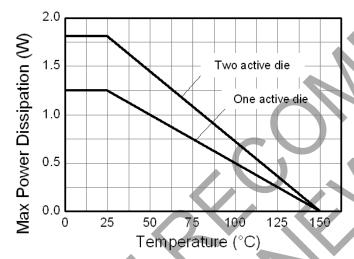
#### **Thermal Characteristics**



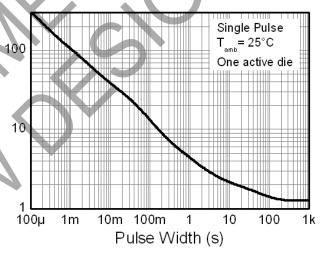
-V<sub>DS</sub> Drain-Source Voltage (V) **P-channel Safe Operating Area** 



# **Transient Thermal Impedance**



**Derating Curve** 



**Pulse Power Dissipation** 

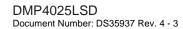
Maximum Power



## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-40	_	_	V	I <sub>D</sub> = -250μA, V <sub>G</sub> S = 0V	
Zero Gate Voltage Drain Current	IDSS	_	_	-1.0	μΑ	V <sub>DS</sub> = -40V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	Igss	_		±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	VGS(TH)	-0.8	-1.3	-1.8	V	$I_D = -250\mu A$ , $V_{DS} = V_{GS}$	
Static Drain-Source On-Resistance (Note 12)	Dagger		18	25	mΩ	Vgs = -10V, ID = -3A	
Static Drain-Source On-Resistance (Note 12)	RDS(ON)		30	45	11152	$V_{GS} = -4.5V$ , $I_{D} = -3A$	
Forward Transconductance (Notes 12 & 13)	<b>g</b> FS	_	16.6		S	$V_{DS} = -5V, I_{D} = -3A$	
Diode Forward Voltage (Note 12)	V <sub>SD</sub>	_	-0.7	-1.0	V	$I_S = -1A$ , $V_{GS} = 0V$	
DYNAMIC CHARACTERISTICS (Note 13)							
Input Capacitance	Ciss		1640	_			
Output Capacitance	Coss	_	179	+	pF	$V_{DS} = -20V$ , $V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	Crss	_	128			1 - (14)12	
Gate Resistance	Rg		6.43		Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (Note 14)	Qg	_	14.0			VGS = -4.5V	
Total Gate Charge (Note 14)	Qg	_	33.7		nC	Vps = -20V	
Gate-Source Charge (Note 14)	Qgs		5.5		IIO	V <sub>G</sub> S = -10V	
Gate-Drain Charge (Note 14)	Qgd	1	7.3	<u> </u>			
Turn-On Delay Time (Note 14)	td(on)	17-1	6.9	1	,		
Turn-On Rise Time (Note 14)	t <sub>R</sub>		14.7			V <sub>DD</sub> = -20V, V <sub>GS</sub> = -10V	
Turn-Off Delay Time (Note 14)	tD(OFF)	7	53.7		ns	I <sub>D</sub> = -3A	
Turn-Off Fall Time (Note 14)	tF	_	30.9				

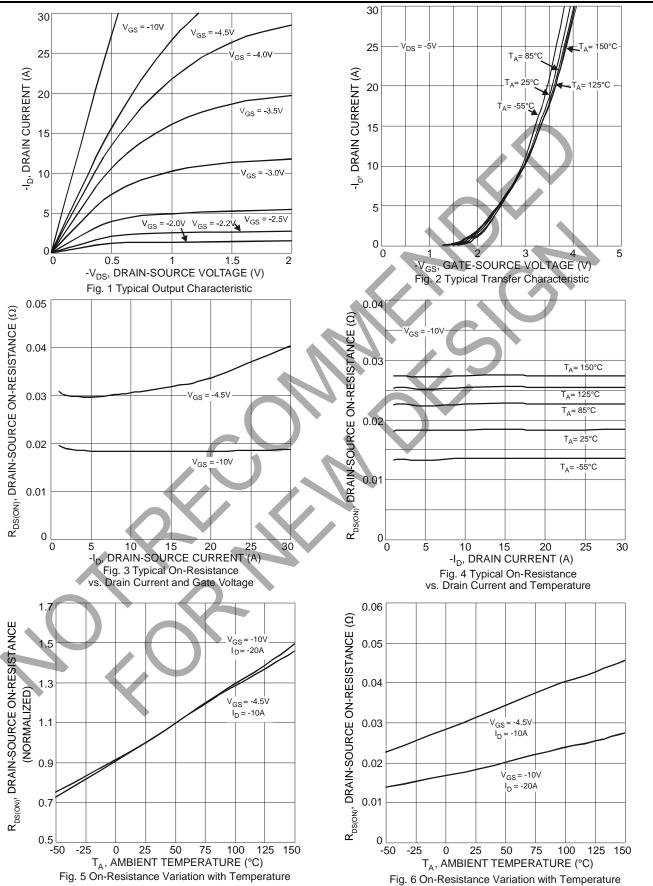
Notes:



<sup>12.</sup> Measured under pulsed conditions. Pulse width ≤ 300μs; duty cycle ≤ 2%.
13. For design aid only, not subject to production testing.
14. Switching characteristics are independent of operating junction temperatures.



# **Typical Characteristics**





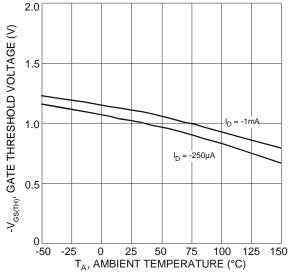
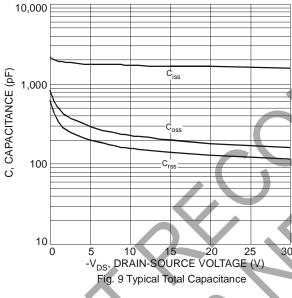
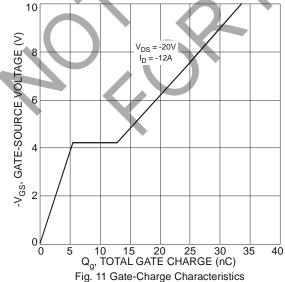
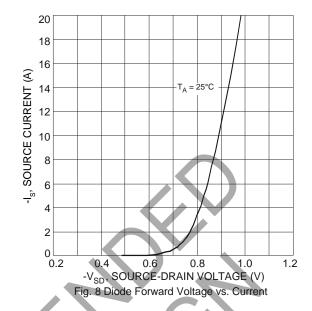
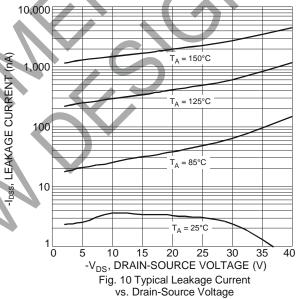


Fig. 7 Gate Threshold Variation vs. Ambient Temperature





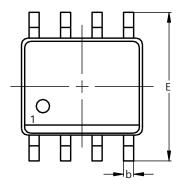


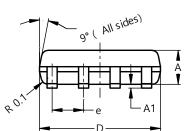


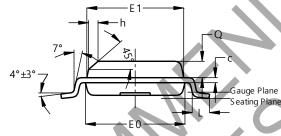


## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.





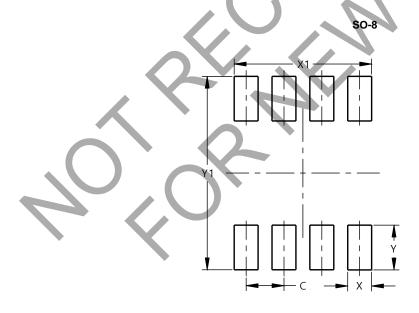


**SO-8** 

SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
Ь	0.30	0.50	0.40		
C	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1 4	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е	1		1.27		
h	1		0.35		
	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All Dimensions in mm					

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
С	1.27			
Х	0.802			
X1	4.612			
Υ	1.505			
Y1	6.50			



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